## Observation of Quantum Hall Valley Skyrm ions

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We report measurements of the interaction-induced quantum Halle ect in a spin-polarized AlAs two-dimensional electron system where the electrons occupy two in-plane conduction band valleys. Via the application of in-plane strain, we tune the energies of these valleys and measure the energy gap of the quantum Hall state at lling factor = 1. The gap has a nite value even at zero strain and, with strain, rises much faster than expected from a single-particle picture, suggesting that the lowest energy charged excitations at = 1 are "valley Skyrm ions".

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In a two-dimensional electron system (2DES) with a spin SU(2) symmetry, electron-electron interaction causes a dramatic deviation from the single-particle physics. For example, the large Coulomb energy cost of a spin ip results in a large excitation gap for the = 1 quantum Hallstate (QHS) even in the lim it of zero Lande g-factor[1, 2, 3, 4, 5, 6]. A nother consequence of this energy cost is that the charged excitations at = 1 have a non-trivial long-range spin order, with a slow rotation of the spin along the radial direction [2]. The size (s) of such a spin texture, or "Skyrm ion", is the number of electrons participating in the excitation, and depends on the ratio of the Coulomb energy to the Zeem an energy [2, 3, 4, 5, 6]. The larger the Zeem an energy, the less preferable it is for the Skym ion to form, and s tends to one as the g-factor of the 2DES is su ciently increased. W hile in the context of a 2DES a Skyrm ion is usually associated with the spin degree of freedom, these excitations should exist in any system whose Hamiltonian has an SU (2) sym m etry [2, 7].

In a 2DES with two equivalent and energy degenerate conduction band valleys, there is a direct analogy between the valley index (isospin) and the electron spin. Indeed, it has been argued that, since rotations in the valley isospin space leave the electron Hamiltonian unchanged, a 2D ES with a valley degree of freedom contains a hidden SU (2) sym m etry [8]. In a two-valley system, an externally applied strain has the same e ect on the valleys as the magnetic eld has on the electron spins; the strain breaks the isospin SU (2) symmetry by lifting the energy degeneracy between the valleys. In this Letter, we directly probe the e ects of interaction on a 2DES conned to an A IAs quantum well where the electrons occupy two valleys. V ia the application of sym m etry breaking in-plane strain, we tune the energies of these valleys and measure the = 1 Q H S energy gap. The gap's dependence on strain provides experim ental evidence that the excitations of this QHS are valley Skyrm ions (valley textures).

A IAs is an indirect gap semiconductor in which the electrons occupy multiple valleys at the X-point of the B rillouin zone. The constant energy surface in bulk A IAs

consists of three highly anisotropic ellipsoids (six half-ellipsoids) with their major axes along the < 100> crystal directions; we designate these valleys by their major axis' direction. The longitudinal and transverse e ective masses of the electrons in these valleys are 1 and 0.2, respectively, in units of the free electron mass. While the valleys in bulk A lAs are energy degenerate, this degeneracy is lifted when the electrons are connected a 2D layer. In a quantum well grown on top of a GaAs (001) wafer, only the [100] and [010] valleys are occupied for well widths greater than 5 nm [9]. This is dierent from the Si (001) MOSFET (metaloxide semiconductor eld-e ect transistor), in which the two valleys with the out-of-plane major axes are occupied.

We study 2D electrons in an 11 nm-wide, modulation doped A IAs quantum well grown on a GaAs (001) substrate using molecular beam epitaxy [10]. The electrons are conned to A IAs by two A  $l_{0.4}$ Ga $_{0.6}$ As barrier layers. We inject current into the 2DES through alloyed AuGeNi contact pads and measure the longitudinal resistance on an etched Hallbarmesa aligned with [100]. The sample is cooled in a pumped  $^3$ He system that allows us to perform measurements in the temperature (T) range between 0.3 K and 6 K. The typicalmobility of our samples is between 8 and 15 m $^2$ /Vs for the electron concentration n=2.6  $10^{11}$  cm $^2$  at T=0.3 K [11].

To control the energy splitting between the valleys, we strain the sample by gluing it to one side of a PZT-5H piezoelectric stack (piezo) with the sample's [100] direction aligned with the poling direction of the piezo, as shown in Fig. 1 (a). The voltage-induced strain change of the piezo allows us to in situ and continuously vary the in-plane strain applied to the sample [12] and thereby lift the valley degeneracy. As shown schematically in Fig. 1 (a), by applying tension along the [100] direction, we induce a transfer of electrons from the [100] valley into the [010] valley; the total density of the 2D ES, however, remains costant to better than 1%. The single-particle valley splitting,  $E_v$ , can be expressed in the form  $E_{2xv}$ , where  $E_2 = 5.8$  eV is the shear deform ation potential for A lAs [13] and xy is the di erence in the strain along [100] and [010]. We determ ine  $E_{v}$  to within an accuracy of

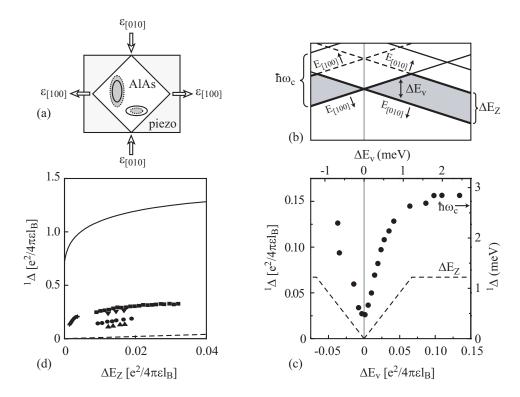


FIG. 1: (a) In-plane strain breaks the valley energy degeneracy; e.g., tension along [100] results in a transfer of electrons from the [100] valley to the [010] valley. (b) Single-particle fan diagram for the A As 2DES using band parameters. (c) Single-particle (dashed lines) and measured (circles) = 1 Q HS gap, 1, as a function of the single-particle valley splitting, E  $_{\rm v}$ , for n = 2:55  $_{\rm 10}^{11}$  cm  $_{\rm 2}^{2}$ . 1 and E  $_{\rm v}$  are given both in meV (top and right axes) and also in units of the Coulomb energy e<sup>2</sup>=4  $_{\rm 1}^{2}$ , where = 10  $_{\rm 0}$  is the dielectric constant of A As and  $_{\rm 1}^{2}$  = (h=eB) $_{\rm 1}^{1-2}$  is the magnetic length; in our experiments, B = 10:5 T and e<sup>2</sup>=4  $_{\rm 1}^{2}$  = 18.2 meV. (d) 1 vs. E  $_{\rm 2}$  for spin Skyrm ions in a single-valley 2DES. The dashed line is the single-particle Zeem an splitting. The theoretical prediction for the Skyrm ion excitation energy is shown by the solid curve and the led symbols show the experimentally determined gaps at = 1 (see text).

0.1 m eV from the oscillations of the sam ple's resistance at high integer lling factors as a function of strain [12] and corroborate it with the Fourier analysis of Shubnikov-de H aas oscillations, the zero-eld piezoresistance data [14], and our calibration of the piezo-induced strain [12].

Before presenting the experim ental data, it is instructive to describe the fan diagram of the A IAs 2DES as a function of strain-induced valley splitting in a noninteracting, single-particle picture [Fig. 1 (b)]. The magnetic eld perpendicular to the plane of the 2D ES quantizes the orbital motion of the electrons and forces them to occupy a discrete set of energy levels separated by the cyclotron energy,  $h!_c = heB = m$  , where m = 0.46 is the cyclotron e ective m ass in A IA s [15]. There are four sets of these Landau levels, one for each spin and valley com bination. The energy splitting between oppositely polarized spins is controlled through  $E_Z = g_{b\ B} B$  (band g-factor  $g_b = 2$ ), while the levels corresponding to di erent valleys are separated by  $E_v$ . When xv = 0, in the single-particle picture of Fig. 1 (b), the energy degeneracy of the Landau levels associated with dierent valleys implies that there is no = 1QHS.As the applied strain

increases and breaks the valley degeneracy, the  $\,=\,1\,$  QHS gap  $(^{1}$ ) develops. For E  $_{\rm V}$  < E  $_{\rm Z}$  ,  $^{1}$  should increase linearly with strain and be equal to E  $_{\rm V}$ . For su ciently large strains such that E  $_{\rm V}$  exceeds E  $_{\rm Z}$  ,  $^{1}$  should be equal to E  $_{\rm Z}$  , independent of strain .

The results of our measurements are in sharp contrast to the simple, non-interacting picture described above. Experimentally, we determine  $^1$  from the activated T-dependence of the longitudinal resistance, R  $_{\rm xx}$ , according to R  $_{\rm xx}$  exp (  $^1$  =2k  $_{\rm B}$  T). This gap is plotted in Fig. 1 (c) as a function of E  $_{\rm v}$ . The measured  $^1$  diers from the single-particle picture [dashed curve in Fig. 1 (c)] in three important aspects;  $^1$ : (1) is nite even when there is no applied strain, (2) rises with the applied strain much faster than expected, and (3) saturates at a value which is closer to h!  $_{\rm C}$  than to E  $_{\rm Z}$ . As we discuss in the remainder of the paper, these features of the data are all consistent with the many-body origin of  $^1$  and the presence of valley Skyrm ions at small values of strain [16].

Since there are no explicit calculations for the dependence of  $^1$  on  $\ E$   $_{\rm v}$  , we compare our data to the de-

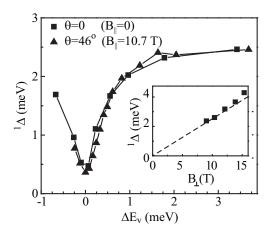


FIG. 2: Dependence of  $^1$  on E  $_{\rm V}$  for an A IA s 2D ES with n = 2.55  $10^{11}$  cm  $^2$  at dierent tilt angles. Single-particle E  $_{\rm Z}$  at = 1 is 1.22 m eV and 1.75 m eV for = 0 and = 46°, respectively. Inset shows a comparison between  $^1$  (squares) and h! $_{\rm C}$  (dashed line) measured at = 0 as a function of perpendicular magnetic eld (density) for a 2D ES with only the [010] valley occupied (E  $_{\rm V}$  = 3.4 m eV).

pendence of  $^1$  on E  $_{\rm Z}$  in a system which has a spin degree of freedom but no valley degree of freedom [4, 6]. In Fig. 1 (d), we show the theoretical prediction for 1 (solid line) that includes the e ects of electron-electron interaction [6]. Even when  $E_Z = 0$ , 1 is nonzero and has a value of 0.63 in units of the Coulom b energy. This is an interaction-induced gap, and rises rapidly as a function of  $E_{z}$ , with the slope of the  $^{1}$  vs.  $E_{z}$  curve equal to the Skym ion size s. The qualitative agreem ent between the theoretical predictions and the measured 1 in GaAs and ALGaAs 2DESs [Lled symbols in Fig. 1 (d)] are widely interpreted as evidence for the existence of QHS spin Skyrm ions [4, 5, 6]. The striking resemblance between the data of Figs. 1 (c) and (d) suggests the presence of QHS "valley Skym ions" in AlAs 2DES.W ith this interpretation, the value of s for the valley Skym ions in our 2DES is 4.3 at E  $_{v} = (e^{2} = 4 + \frac{1}{4}) = 0.01$ , comparable to s = 5 for the spin Skyrm ions in GaAs 2DESs at  $E_{Z} = (e^{2} = 4 + \frac{1}{2}) = 0.01 [4].$ 

In our experiments, as in previous measurements of spin Skyrmions in single-valley systems [4, 5, 6], we not that the measured values for 1 are only a small fraction of the Coulomb energy, in sharp contrast to the theoretical prediction [see Fig. 1 (d)]. The strongly depressed experimental gap for = 1 in a non-idealized 2DES is attributed to the combination of the elects of the nite wavefunction thickness along the connement direction, Landau levelmixing, and disorder [6, 17]. In AlAs, the effect of Landau levelmixing should be particularly in portant since the Coulomb energy in our experiment is much larger than the separation between the single-particle energy levels.

We now address whether the spin degree of freedom

a ects the strength of the = 1 Q H S in our samples at both large and small values of E  $_{\rm v}$  . In Fig. 1 (c) we note that, for large values of  $E_{v}$ , where the electrons occupy only the [010] valley, the measured 1 saturates at a value that is close to h! c rather than E z, contrary to what we would expect from the fan diagram of Fig. 1 (b). We have measured this saturation value as a function of the 2DES density (Fig. 2 inset), and we nd that it is indeed always close to h!c in our accessible density range. This observation is not surprising. It is consistent with previous measurements [18, 19] which indicate that, thanks to interaction,  $E_{\rm Z}$  is greatly enhanced in A IAs 2D ESs and is indeed larger than h! c for the param eters of our sam ple. Therefore, in the lim it of very large  $\, \, \text{E} \, _{\, \text{V}} \, ,$ the nearest single-particle energy level is h!c above the ground state energy. Our data indicate that once 1 reachesh! c, it remains xed ath! c and no longer shows an enhancem ent over the single-particle gap.

To further understand the role of electron spin in our 2D ES, and to ensure that our data of Fig. 1 (c) are not inuenced by the spin degree of freedom, we performed the following experiment. We measured  $^1$  as we increased the Zeem an energy by tilting the normal of the 2D ES by degrees with respect to the magnetic eld while keeping the perpendicular component of the eld B  $_2$  (and thus h! $_{\rm c}$ ) constant [20]. In Fig. 2, we show the measured  $^1$  for = 0 (squares) and = 46 (triangles). We display the data at = 46 shifted by +0.27 meV in E  $_{\rm V}$  with respect to the = 0 data [21]. As can be clearly seen,  $^1$  in una ected by a 43% increase of E  $_{\rm Z}$ . These data thus indicate that the dependence of  $^1$  on E  $_{\rm V}$  seen at small values of strain in Fig. 1 (c) is primarily a result of the valley interaction and not spin e ects.

Our  $R_{xx}$  vs. magnetic eld data (Fig. 3), taken at various values of strain, reveal additional interesting features. The low temperature (T = 0.3 K) traces shown in the main gure exhibit several strong Q H Ss at various llings, including one at the fractional lling The strongest Q H S clearly occurs at = 1 in the entire range of applied strains, attesting to the robustness of this Q H S even in the lim it of zero strain. In traces taken at higher tem perature (T = 2 K), plotted in the inset, the = 1 m in im um is indeed the most prominent feature of the data. The T = 2K data show a weakening of the = 1 m in im um when the strain is small, consistent with values of Fig. 1 (c). M ore rem arkably, we observe that for small strains there are in fact two minima near = 1, one exactly at = 1 and the other at a slightly lower eld. The side m in im um, whose resistance value does not follow a simple, therm ally activated behavior, disappears with increasing magnitude of E  $_{\mathrm{v}}$ . The appearance of a double minimum near a QHS has been previously associated with a phase transition between two competing QHSs, such as between spin-polarized and unpolarized QHSs at = 8=5 [22] or at = 2=3 [23] in G aA s 2D ESs. We do not know if the double minimum we observe is

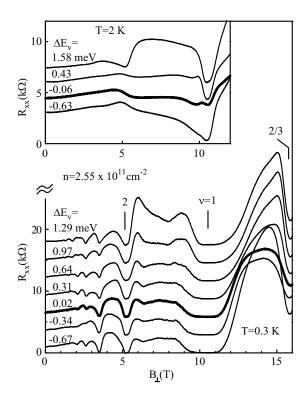


FIG. 3: M agnetoresistance of the A  $\rm I\!A$  s 2D ES for di erent values of applied strain at T = 0.3 K (m ain gure) and 2 K (inset). The value of E  $_{\rm V}$  is indicated for each trace; the bold traces correspond to the sm allest m agnitude of E  $_{\rm V}$ . Traces are vertically o set from each other for clarity.

a signature of a phase transition in the A IAs 2DES; we note however, that competing states in 2DESswith (spin) SU (2) symmetry have been theoretically suggested [17].

In conclusion, we not that electron-electron interaction strongly modi es the excitations of the = 1 Q H S of a two-valley 2D E S. O ur m easurem ents of the energy gap for this Q H S in an A  $\mathbb{I}A$  s 2D E S as a function of applied strain suggest that these excitations involve valley Skyrm ions. In closing, we note that while nuclear magnetic resonance measurements serve as a powerful probe of spin Skyrm ions [3], they cannot be used to detect valley Skyrm ions. It may be possible, however, to use electromagnetic radiation to couple to the valley Skyrm ions, as rotations in the valley isospin space should result in a change in the conductivity tensor of the A  $\mathbb{I}A$  s 2D E S.

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